NSN 5961-00-005-2508

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-005-2508 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.050 inches **Overall Width:** 0.150 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-89 **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open all transistor and 35.0 collector-to-emitter, substaining voltage, base open-circuited all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**